



# TESSERACT: dark matter detection with transition edge sensors and multiple targets

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The TESSERACT project Recent progress Coming up next Direct search for low-mass Dark matter search with a Two-channel devices Second helium detector for dark matter 10g, 10eV threshold silicon • Transition Edge Sensors calibration detector (TESs) with Sub-EV ~1eV threshold detector Underground experiment •

- **Resolution And Cryogenic** Targets
- Polar crystal -- SPICE
- Superfluid helium -- HeRALD

- Low energy excess events
- Low Tc, low stress films
- Proof-of-principle HeRALD • detector operation
- preparation





## The TESSERACT project





Low threshold

Target with light element

## Polar crystal: optical phonons, dark photon coupling.







Low threshold

Target with light element

Polar crystal: optical phonons, dark photon coupling.

→ Develop a low-threshold (sub-eV) sensor for multiple cryogenic targets: TES based athermal phonon sensors!



### **TESSERACT & Athermal phonon sensor**



#### **TESSERACT & Athermal phonon sensor**



## **TESSERACT: SPICE**

Use polar crystals as targets.

- Al<sub>2</sub>O<sub>3</sub>
- GaAs

GaAs is also a great cryogenic scintillator, can use photons to do background discrimination.

Currently use silicon substrate for fast R&D:

- Tune TES film Tc to achieve sub-eV energy threshold. 55mK Tc  $\rightarrow$  20mK Tc
- Understand noise and background.

GaAs and  $\mathrm{Al_2O_3}$  R&D in parallel.





## **TESSERACT: HeRALD**

Use superfluid helium as target. Use silicon photon detector as sensor.

- 16eV scintillation photon
- Quantum evaporation from rotons and phonons

Currently focus on understanding the detector response

- Roton detection efficiency
- Quantum evaporation gain
- Superfluid helium response







## **Recent progress**

## Dark matter search with 10g, 10eV threshold Si detector

10-26

 $10^{-28}$ 

Same detector for the HeRALD readout.

Large spectrum: Energy region of interest Inset: High energy region with 1.48keV Al k-alpha calibration peak Preliminary limit on nuclear recoil dark matter. Low-energy reach competes with Migdal effects.





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### ~1eV threshold detector

Reduce target mass. Reduce surface coverage.

1cm<sup>2</sup> 1mm thick silicon detectors.

Free-hanging from wire bonds to reduce stress. SPICE 1%: ~273 meV (sigma) energy resolution in phonon system SPICE 0.25%: ~460 meV (sigma) energy resolution in phonon system



CPAD Talk 2023 (stanford.edu)

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CPAD Talk 2023 (stanford.edu)

450 nm Fi

405 nm Fi

405 000

#### Low energy excess events

#### Stress related low energy events.

High stress mounting introduce higher rate. Rate decays exponentially with cold time. Events of same spectrum and decay observed in many experiments. Non-ionizing.

 $\rightarrow$  Hanging device + low stress film.



 $10^{-4}$  $10^{-5}$ 20 120 40 100 60 80 Energy absorbed in TES (eV) 10<sup>1</sup> High Stress, 3 eV to 38 eV rate Low Stress, 3 eV to 38 eV rate 100 High Stress, 85 eV + rate Rate in Bin (Hz) 1-01 Low Stress, 85 eV + rate High Stress, 38 eV to 85 eV rate Low Stress, 38 eV to 85 eV rate  $10^{-2}$  $10^{-3}$ 60 80 100 120 140 arxiv:2208.02790 Time After Cooldown (Hours)

Glue

Stress

High Stress

Low Stress

85+ eV Bin

140

- Corre TTT.

160

Saturation

3-38 eV Bin 38-85 eV Bin

10<sup>2</sup>

10<sup>1</sup>

100

Counts/(eV s) 10<sup>-1</sup>

10-3

#### Low energy excess events

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The low coverage device's energy resolution improves over time as the LEE rate decreases!

The LEE spectrum extends to below threshold.

e (W/rt(Hz))

The LEE also prevent us reaching the • theoretical energy resolution.





#### Low stress low Tc films

First attempt with tungsten film. Low Tc achieved. Not low stress. Good results from Ir/Pt bilayer samples from Argonne National Laboratory.

TES fabrication finished. Tests on going!







## **Proof-of-principle HeRALD detector operation**

Cs superfluid helium stoper demonstrated. Photon and quantum evaporation signals observed. 145eV energy threshold.

Ready to explore very interesting helium physics!

arxiv: 2307.11877





## **Proof-of-principle HeRALD detector operation**

Cs superfluid helium stoper demonstrated.

Photon and quantum evaporation signals observed. 145eV energy threshold.

Ready to explore very interesting helium physics!

Clear discrimination between electron recoil and nuclear recoil.







## Coming up next

### **Two channel devices**

Path to LEE background rejection

Helium readout with split CPD



Two TES channels on one silicon substrate Need to improve triggering algorithm





#### Second HeRALD detector at LBL

- Improved design for better Cs deposition.
- 2 by 2 readout arrays on top and bottom.
- Helium electron recoil and neutron recoil calibration.
- Quantum evaporation efficiency and gain calibration.





#### Photos for reference

**BUI Tuan Khai** 

From https://www2.kek.jp/gup/en/member/



Maurice

Garcia-Sciveres

Koji Ishidoshiro

Suerfu Burkhant

uerfu-at-nost

OUP Deputy Principal

Kaori Hattori

OUP Principal Investig Research Institut

**Underground experiment preparation** 

#### **Underground labs**

US - SURF Space ready in 2025 Planning for 2 payloads

France - Modane - LSM Project presented to French community since Oct 2022. Planning for 1~2 payloads.

UP Principal Investigator Associate Professor KEK, IPNS Institution me Hel.in Japan - Kamioka Commissioning: ~mid 2024. Science payload: ~10g-yr exposure ~20eV threshold.

Existing

To be adde



## **Underground experiment preparation**

#### Low background environment

#### **1 DRU shielding**

Simulation + engineering design



#### Zero vibration cooling



#### **EMI/RF/IR** shielding

Parasitic noise power from EMI/RF/IR is the limiting factor to go to lower energy threshold.

- Improve fridge RF tightness.
- Improve detector holder IR tightness.
- Filter EMI/RF/IR from TES bias.



#### Conclusion

- TESSERACT has a strong collaboration and we are building up momentum.
- The goal is to explore the large parameter space from 1GeV to 1keV dark matter mass with various target materials.
- 10g, 10eV silicon device obtained world-leading results.
- Results from ~1eV threshold device on the way.
- Successfully demonstrated superfluid helium detector with film stopper and quantum evaporation signals. Next iteration detector will be ready soon.
- Reduce background:
  - Reduce film stress.
  - Reject single events in two-channel devices.
- Simulation and engineering design for underground experiments goes in parallel.

#### Thank you! Questions?





## **Back up**

### HeRALD detector concept and helium response

#### Phys. Rev. D 100, 092007 (2019)





#### **HeRALD** detector quantum evaporation

#### Phys. Rev. D 100, 092007 (2019)





#### Athermal phonon sensor energy resolution

TES noise is limited by the thermal fluctuation noise of the thermal link G between the TES and the bath.

$$\sigma_E \sim \frac{\sqrt{4k_b T_c^2 G(\tau_{collect} + \tau_{sensor})}}{\epsilon_{collect} \epsilon_{sensor}}$$

Thermal phonon TES sensor:  $\tau \sim C_{detector}/G \rightarrow \sigma_E \sim T_c^{3/2}$ 

Athermal phonon sensor: Thanks to extra freedoms from the phonon collection fins,  $\tau_{\text{collect}}$  can be engineered to match  $\tau_{\text{sensor}}$  (the time scale of electrical-thermal feedback)  $\rightarrow \sigma_{E} \sim T_{c}^{3}$ 

- Lower Tc
- Optimization of phonon and quasiparticle collection efficiency.

#### LEE event spectra from various experiments.



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arxiv: 2202.05097

### **Multi-phonon creation in crystals**

#### Gains additional sensitivity at sub-eV



#### **Multi-phonon creation in crystals**



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### **CPDv2** design



TES length	140 µm
TES Thickness	40 nm
TES width	2.5 µm
n <sub>fin</sub>	6
Fin Length	150 µm
Fin Thickness	600 nm
Al/W Overlap	20 µm
N <sub>qet</sub>	673
Active Surface Area	0.68%
Passive Surface Area	0.18%
R <sub>n</sub>	200 mΩ
QP Abs Efficiency	52%
Tot Efficiency	18% (Simulated)